



## COMBINED DECLARATION AND POWER OF ATTORNEY

This declaration is of the fe	ollowing type:			
national stage	design supplemental of PCT continuation continuation	n-in-part		
As a below named invento	r, I hereby declare that			
My residence, post office a	address, and citizenship are as sta	ted below next to my nan	ne.	
inventor (if plural names of	, first, and sole inventor (if only are listed below) of the subject m Semiconductor Device a	natter which is claimed a	nd for which a pat	ent is sought
the specification of which:				
was file on was des	ed hereto. d on (if app cribed and claimed in PCT Inte  (if any).	as Serial No plicable). ernational Application N and as amended purs	and volume	was amended ticle 19 on
·	and understand the contents of the			
I acknowledge the duty to above in accordance with	o disclose information that is many of CFR §1.56.	aterial to the examination	on of the application	on identified
certificate or of any PCT i States of America listed be design registration, or inve- country other than the Uni	nefits pursuant to 35 USC §119(international patent application(s) elow and have also identified belentor's certificate or any PCT inted States of America filed by moom which the benefit of priority is	) designating at least one low any foreign applicate ernational patent applicate e for the same invention	e country other that ion(s) for patent, ution(s) designating	n the United stility model, g at least one
	reign patentșu iliptivamo Priications, benefit clai			
COUNTRY	PRIOR FOREIGN APPLICATION	DATE OF FILING! (day,month,year)	PRIORITY CI UNDER 35 US	
Japan	P 11-201609	15/07/1999	X YES	NO.
			YES	NO
	<b>[</b>		YES	+NO:#

I claim the benefit pursuant to 35 C §119(e) of the following United States proving all patent application(s):

PRIOR U.S. PROVISIONAL PATENT APPLICATIONS, BENEFIT CLAIMED UNDER 35 USC §119(e)					
APPLICATION NO.		DATE OF FILING (day,month,year)			

I claim the benefit pursuant to 35 USC §120 of any United States patent application(s) or PCT international patent application(s) designating the United States of America listed below and, insofar as the subject matter of each of the claims of this patent application is not disclosed in the prior patent application(s) in the manner provided by the first paragraph of 35 USC §112, I acknowledge the duty to disclose material information as defined in 37 CFR §1.56 effective between the filing date of the prior patent application(s) and the national or PCT international filing date of this patent application.

	S. PATENT APPI S DESIGNATING					
U.S. PATENT APPLICATIONS			Status (check one)			
SERIAL NUMBER	U.S	FILING DATE		PATENTED	PENDING	ABANDONED
1.						
2.						
3.						
PCT APPLICATION	ONS DESIGNATI	NG THE U.S.			Status (check or	ie)
PCT APPLICATION NO.	PCT FILING :	U.S. SERIAL N ASSIGNED (if any)	los.	PATENTED	PENDING	ABANDONED
4.						
5.				<del></del>		· · · · · · · · · · · · · · · · · · ·
6.	·					

As a named inventor, I appoint the following attorneys to prosecute this application and transact all business in the Patent and Trademark Office connected with this patent application.

John M. Belz, Reg. 30,359 Jeffrey A. Wyand, Reg. 29,458 Jeremy M. Jay, Reg. 33,587

Michael H. Tobias, Reg. 32,948 Gregory A. Hunt, Reg. 41,085 Patrick R. Jewik, Reg. 40,456 Joseph S. Ostroff, Reg. 39,321

I further direct that correspondence concerning this application be sent to:

LEYDIG, VOIT & MAYER, LTD.
700 Thirteenth Street, N.W., Suite 300
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Post Office Address:

I authorize my attorneys to accompand follow instructions from AOYAMA ARTNERS regarding any matter related to the preparation, examination, grant, and maintenance of the patent application identified above, any continuation, continuation-in-part, or divisional patent application based on the patent application identified above, and any patent issuing from that patent application, until I or my assigns withdraw this authorization in writing.

I declare that all statements made herein of my own knowledge are true, that all statements made on information and belief are believed to be true, that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code, and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole or first inventor: Satoshi SUZUKI	
Inventor's signature Satoshi Suzuki	
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Inventor's signature <u>Jetsuo Kunii</u>	•
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Full name of third joint inventor, if any:	
Inventor's signature	
Date	Country of Citizenship:
Residence:	

**PATENT** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

#5 Pla 10.27-00

In re application of:

SUZUKI et al.

Serial No:

None assigned

Filed:

July 11, 2000

For:

Semiconductor Device And Process

For Manufacturing The Same

## ASSOCIATE POWER OF ATTORNEY

Assistant Commissioner for Patents Washington, D.C. 20231

Dear Sir:

I, Jeffrey A. Wyand, attorney of record in the referenced patent application, grant an

Associate Power of Attorney to XAVIER PILLAI, Registration Number 39,799.

Respectfully submitted,

LEYDIG VOIT & MAYER

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